

Modeling of a UHF RFID Tag

UHF RFID tags are widely used for identifying and tracking animals. This example simulates a passive radio-frequency identification (RFID) tag for the UHF frequency range.

With respect to the chip transponder's complex impedance, a reflection coefficient is computed. This is done using an approach that differs from the conventional scattering parameter analysis method by a real reference impedance value.

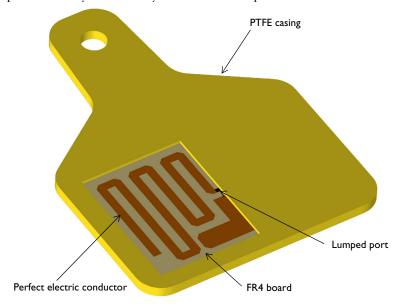


Figure 1: The RFID tag's geometry consists of copper traces patterned on an FR4 board that is enclosed by a low dielectric PTFÉ case. The surrounding air domain and perfectly matched layers, which are required for the simulation, are not included in this figure.

Model Definition

In this example, the RFID tag's operating frequency is 915 MHz. At this frequency, the metal part of the RFID tag can be modeled as a perfect electrical conductor (PEC), because while the copper traces patterned on the FR4 board are geometrically very thin, they are much thicker than the skin depth.

The entire circuit board is inserted inside a lossless PTFE casing. The tag is modeled in a spherical air domain, which is enclosed by perfectly matched layers (PML) that absorb all outgoing radiation from the tag.

A lumped port with a reference impedance of 50 Ω is used on the location of an RFID chip. This is done to excite the tag and evaluate the input impedance of the tag's antenna part, which is modeled as a meander line. An additional copper strip is placed adjacent to the meander line to control the impedance.

The conventional S-parameter works well only with a real reference impedance. However, the RFID chip's impedance is complex and the calculated S-parameter is not physical when a complex port reference impedance is used.

In Ref. 1, the power wave reflection coefficient term is introduced. It is applicable for evaluating the matching properties of an RFID tag:

$$\Gamma = \frac{Z_l - Z_{\text{ref}}^*}{Z_l + Z_{\text{ref}}}$$

where Z_l is the complex load impedance and Z_{ref} is the complex reference impedance.

Results and Discussion

Figure 2 shows the default E-field norm on the xy-plane. The field distribution plot indicates that the electric field is symmetrically confined along the meander line, as well as in the area between the meander line and impedance matching strip.

The far-field radiation pattern of the tag is shown in Figure 3. Noticeably, the tag's radiation pattern looks very similar to the radiation pattern of a half-wave dipole antenna.

The evaluated impedance of the tag is around $17+j124 \Omega$ and the power wave reflection coefficient, in dB, is below -15 dB.

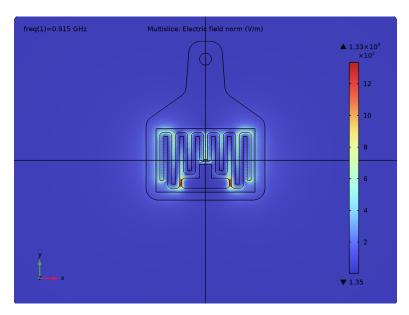


Figure 2: The E-field norm plot shows where the field is strongly confined in the tag.

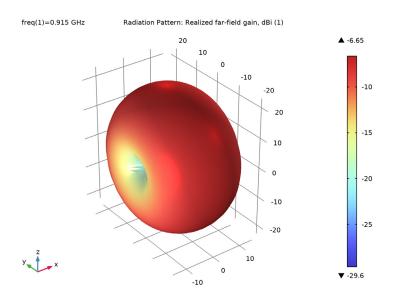


Figure 3: The far-field radiation pattern resembles that of a half-wave dipole antenna.

Reference

1. K. Kurokawa, "Power Waves and the Scattering Matrix," *IEEE Transactions on Microwave Theory and Techniques*, Volume 13, 1965.

Application Library path: RF Module/Antennas/uhf rfid tag

Modeling Instructions

From the File menu, choose New.

NEW

In the New window, click Model Wizard.

MODEL WIZARD

- I In the Model Wizard window, click **3D**.
- 2 In the Select Physics tree, select Radio Frequency > Electromagnetic Waves, Frequency Domain (emw).
- 3 Click Add.
- 4 Click 🔵 Study.
- 5 In the Select Study tree, select General Studies > Frequency Domain.
- 6 Click M Done.

STUDY I

Step 1: Frequency Domain

Define the study frequency ahead of performing any frequency-dependent operation such as building mesh. The physics-controlled mesh uses the specified frequency value.

- I In the Model Builder window, under Study I click Step I: Frequency Domain.
- 2 In the Settings window for Frequency Domain, locate the Study Settings section.
- 3 In the Frequencies text field, type 915[MHz].

GLOBAL DEFINITIONS

Parameters 1

I In the Model Builder window, under Global Definitions click Parameters 1.

- 2 In the Settings window for Parameters, locate the Parameters section.
- **3** In the table, enter the following settings:

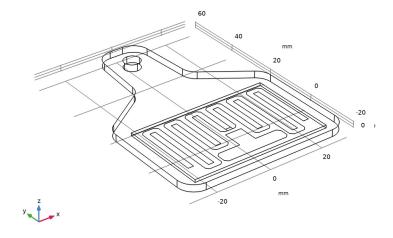
Name	Expression	Value	Description
Zc	15-j*125[ohm]	(15-125i) Ω	Chip impedance

GEOMETRY I

- I In the Model Builder window, under Component I (compl) click Geometry I.
- 2 In the Settings window for Geometry, locate the Units section.
- **3** From the **Length unit** list, choose **mm**.

Import I (impl)

- I In the Geometry toolbar, click Import.
- 2 In the Settings window for Import, locate the Source section.
- 3 Click **Browse**.
- **4** Browse to the model's Application Libraries folder and double-click the file uhf rfid tag.mphbin.
- 5 Click Import.
- **6** Click the Wireframe Rendering button in the Graphics toolbar.



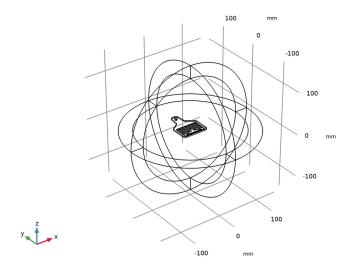
Add a sphere for the air domain surrounding the RFID tag and perfectly matched layers that will be configured later on.

Sphere I (sph I)

- I In the Geometry toolbar, click Sphere.
- 2 In the Settings window for Sphere, locate the Size section.
- 3 In the Radius text field, type 150.
- **4** Click to expand the **Layers** section. In the table, enter the following settings:

Layer name	Thickness (mm)
Layer 1	30

- 5 Click Build All Objects.
- **6** Click the **Zoom Extents** button in the **Graphics** toolbar.



DEFINITIONS

Variables 1

- I In the Model Builder window, under Component I (compl) right-click Definitions and choose Variables.
 - Define a variable for calculating the reflection coefficient between two complex impedances.
- 2 In the Settings window for Variables, locate the Variables section.

3 In the table, enter the following settings:

Name	Expression	Unit	Description
Gamma	<pre>(emw.Zport_1-conj(Zc))/ (emw.Zport_1+Zc)</pre>		Reflection coefficient for complex impedance matching

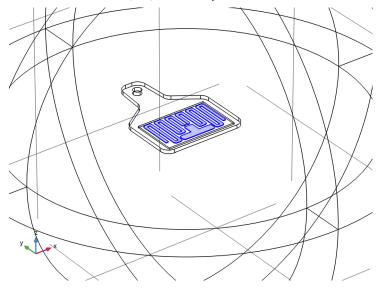
Perfectly Matched Layer I (pml1)

- I In the Definitions toolbar, click MP Perfectly Matched Layer.
- 2 Select Domains 1–4 and 9–12 only. These are all of the outermost domains of the sphere.
- 3 In the Settings window for Perfectly Matched Layer, locate the Geometry section.
- 4 From the Type list, choose Spherical.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN (EMW)

Perfect Electric Conductor 2

- I In the Physics toolbar, click **Boundaries** and choose Perfect Electric Conductor.
- 2 Click the 🔍 Zoom In button in the Graphics toolbar, a couple of times to get a clear view of the RFID tag.
- 3 Select Boundaries 25, 27, and 54 only.



Lumbed Port I

- I In the Physics toolbar, click **Boundaries** and choose **Lumped Port**.
- 2 Select Boundary 35 only.

For the first port, wave excitation is **on** by default.

- 3 Click the **Zoom Extents** button in the **Graphics** toolbar.
- 4 Click the **Q** Zoom In button in the Graphics toolbar.

Far-Field Domain 1

In the Physics toolbar, click **Domains** and choose Far-Field Domain.

ADD MATERIAL

- I In the Materials toolbar, click Radd Material to open the Add Material window.
- 2 Go to the Add Material window.
- 3 In the tree, select Built-in > Air.
- **4** Click the **Add to Component** button in the window toolbar.
- 5 In the tree, select Built-in > FR4 (Circuit Board).
- **6** Click the **Add to Component** button in the window toolbar.
- 7 In the Materials toolbar, click Radd Material to close the Add Material window.

MATERIALS

FR4 (Circuit Board) (mat2)

Select Domain 7 only.

Material 3 (mat3)

- I In the Model Builder window, right-click Materials and choose Blank Material.
- 2 Select Domain 6 only.
- 3 In the Settings window for Material, locate the Material Contents section.

4 In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Relative permittivity	epsilonr_iso; epsilonrii = epsilonr_iso, epsilonrij = 0	2.1	I	Basic
Relative permeability	mur_iso; murii = mur_iso, murij = 0	1	I	Basic
Electric conductivity	sigma_iso; sigmaii = sigma_iso, sigmaij = 0	0	S/m	Basic

MESH I

In the Model Builder window, under Component I (compl) right-click Mesh I and choose **Build All.**

To see the meshed structure of the device, remove some boundaries from the view.

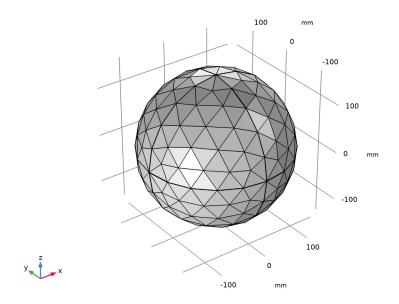
DEFINITIONS

Hide for Physics 1

- I In the Model Builder window, right-click View I and choose Hide for Physics.
- 2 In the Settings window for Hide for Physics, locate the Geometric Entity Selection section.
- 3 From the Geometric entity level list, choose Boundary.
- 4 Select Boundaries 6, 10, 16, 37, 40, and 42 only.

MESH I

In the Model Builder window, under Component I (compl) click Mesh I.



STUDY I

Step 1: Frequency Domain

In the **Study** toolbar, click **Compute**.

RESULTS

Multislice

- I In the Model Builder window, expand the Electric Field (emw) node, then click Multislice.
- 2 In the Settings window for Multislice, locate the Multiplane Data section.
- 3 Find the X-planes subsection. In the Planes text field, type 0.
- 4 Find the Y-planes subsection. In the Planes text field, type 0.
- 5 In the Electric Field (emw) toolbar, click Plot.
- 6 Click the **XY** Go to XY View button in the Graphics toolbar.

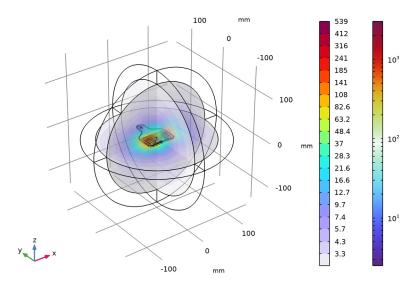
Zoom in a couple of time to get a good view of the RFID tag.

Compare the reproduced plot with Figure 2.

Electric Field, Logarithmic (emw)

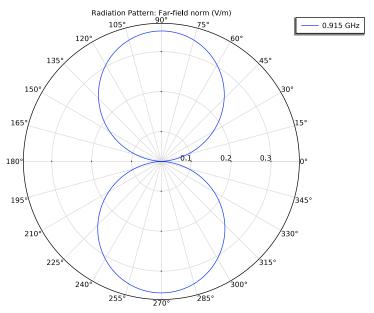
In the Model Builder window, under Results click Electric Field, Logarithmic (emw).

freq(1)=0.915 GHz Surface: 1 (1) Multislice: Electric field norm (V/m) Surface: Electric field norm (V/m)



2D Far Field (emw)

I In the Model Builder window, click 2D Far Field (emw).



The E-plane radiation pattern resembles that of a dipole antenna.

Radiation Pattern I

- I In the Model Builder window, expand the 3D Far Field, Gain (emw) node, then click Radiation Pattern I.
- 2 In the Settings window for Radiation Pattern, locate the Evaluation section.
- 3 Find the Angles subsection. In the Number of azimuth angles text field, type 40.
- 4 In the 3D Far Field, Gain (emw) toolbar, click on Plot.

DIRECTIVITY

I Go to the **Directivity** window. Reproduce Figure 3.

RESULTS

Global Evaluation 2

I In the Results toolbar, click (8.5) Global Evaluation.

- 2 In the Settings window for Global Evaluation, click Replace Expression in the upper-right corner of the Expressions section. From the menu, choose Component I (compl) > Electromagnetic Waves, Frequency Domain > Ports > emw.Zport_I -Lumped port I impedance - Ω .
- 3 Click **= Evaluate**.

Global Evaluation 3

- I In the Results toolbar, click (8.5) Global Evaluation.
- ${\bf 2}\,$ In the Settings window for Global Evaluation, locate the Expressions section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
20*log10(abs(Gamma))		

4 Click **= Evaluate**.